

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[Microsemi Power Products](#)

[APTGT25DA120D1G](#)

For any questions, you can email us directly:

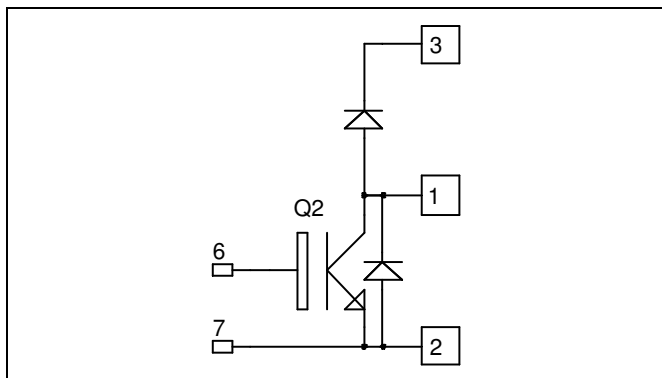
sales@integrated-circuit.com



APTGT25DA120D1

Boost chopper Trench IGBT® Power Module

$V_{CES} = 1200V$
 $I_C = 25A @ T_c = 80^\circ C$



Application

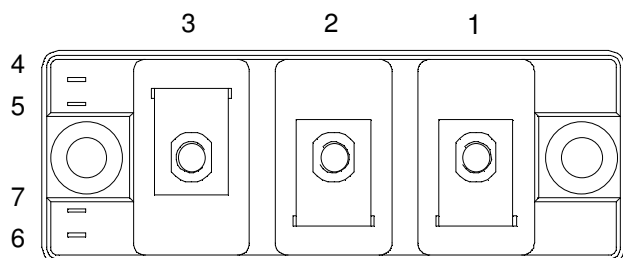
- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Trench + Field Stop IGBT® Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - Avalanche energy rated
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Low stray inductance
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of V_{CESat}



Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage	1200	V
I_C	Continuous Collector Current	$T_C = 25^\circ C$ 40 $T_C = 80^\circ C$ 25	A
I_{CM}	Pulsed Collector Current	$T_C = 25^\circ C$ 65	A
V_{GE}	Gate - Emitter Voltage	± 20	V
P_D	Maximum Power Dissipation	$T_C = 25^\circ C$ 140	W
RBSOA	Reverse Bias Safe Operation Area	$T_J = 125^\circ C$ 50A@1200V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



APTGT25DA120D1

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
BV_{CES}	Collector - Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 4mA$	1200			V
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$			5	mA
$V_{CE(on)}$	Collector Emitter on Voltage	$V_{GE} = 15V$ $I_C = 25A$		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	1.7 2.1	V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1mA$	5.0	5.8	6.5	V
I_{GES}	Gate - Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$			400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{ies}	Input Capacitance	$V_{GE} = 0V$		1.8		nF
C_{oes}	Output Capacitance	$V_{CE} = 25V$		0.1		
C_{res}	Reverse Transfer Capacitance	$f = 1MHz$		0.08		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		150		ns
T_r	Rise Time	$V_{GE} = \pm 15V$		90		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$		550		
T_f	Fall Time	$I_C = 25A$ $R_G = 36\Omega$		130		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)		180		ns
T_r	Rise Time	$V_{GE} = \pm 15V$		100		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$		650		
T_f	Fall Time	$I_C = 25A$ $R_G = 36\Omega$		180		

Reverse diode ratings and characteristics

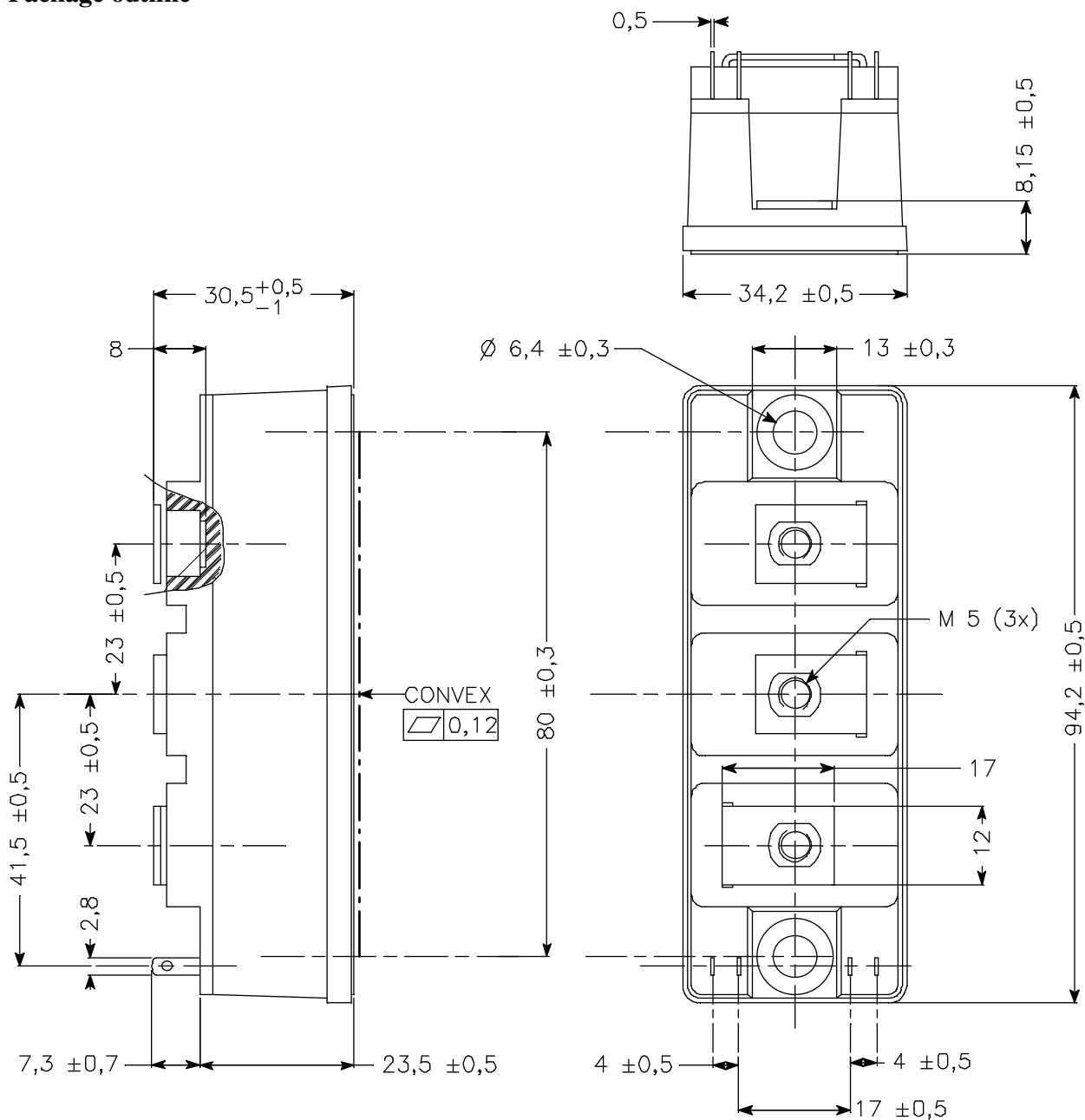
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
V_F	Diode Forward Voltage	$I_F = 25A$ $V_{GE} = 0V$		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	1.6 1.6	V
E_{rec}	Reverse Recovery Energy	$I_F = 25A$ $V_R = 600V$ $di/dt = 990A/\mu s$		$T_j = 125^\circ\text{C}$	2	mJ
Q_{rr}	Reverse Recovery Charge	$I_F = 25A$ $V_R = 600V$ $di/dt = 990A/\mu s$		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	2.7 5	μC

Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
R _{thJC}	Junction to Case		IGBT			0.9	°C/W
			Diode			1.5	
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, I isol<1mA, 50/60Hz			2500			V
T _J	Operating junction temperature range			-40		150	°C
T _{STG}	Storage Temperature Range			-40		125	
T _C	Operating Case Temperature			-40		125	
Torque	Mounting torque	For terminals	M5	2		3.5	N.m
		To Heatsink	M6	3		5	
Wt	Package Weight					180	g

APTGT25DA120D1

Package outline



APT reserves the right to change, without notice, the specifications and information contained herein

APT's products are covered by one or more of U.S. patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522 5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. U.S and Foreign patents pending. All Rights Reserved.